

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (MMBT4401T)
- Ultra-Small Surface-Mount Package
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

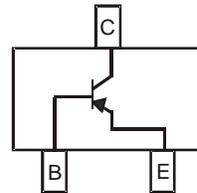
Mechanical Data

- Package: SOT523
- Package Material: Molded Plastic, "Green" Molding Compound
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight: 0.002 grams (Approximate)

SOT523



Top View



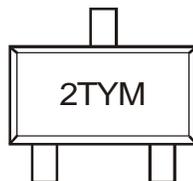
Package Pin Out Configuration

Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
MMBT4403T-7-F	SOT523	2T	7	8	3000	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



2T = Product Type Marking Code
 YM = Date Code Marking
 Y or \bar{Y} = Year (ex: L = 2024)
 M = Month (ex: 9 = September)

Date Code Key

Year	2018	-	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	F	-	L	M	N	P	R	S	T	U	V	W

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current – Continuous (Note 5)	I _C	-600	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	150	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	833	°C/W
Thermal Resistance, Junction to Case (Note 6)	R _{θJC}	96	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
- For a device mounted with the exposed collector pad on minimum recommended pad (MRP) layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady state.
 - Same as Note 5, except the exposed collector pad is mounted on minimum recommended pad layout 2oz copper that is on a single sided 1.6mm FR4 PCB.

Thermal Characteristics and Derating Information

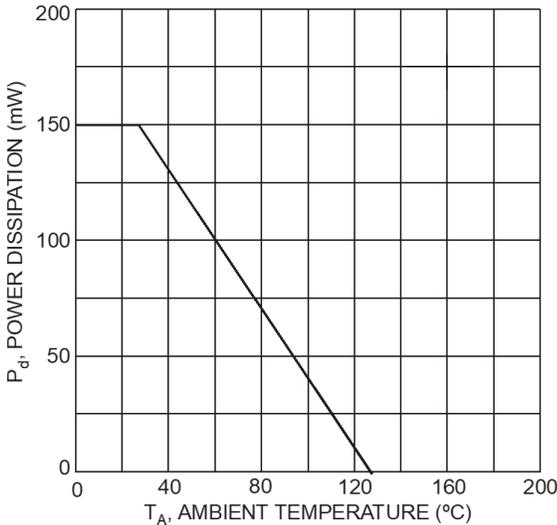


Fig. 1 Power Derating Curve, Total Package

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					
Collector-Base Breakdown Voltage	BV _{CB0}	-40	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	-40	—	V	I _C = -1.0mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	—	V	I _E = -100μA
Collector Cutoff Current	I _{CEX}	—	-100	nA	V _{CE} = -35V, V _{EB(off)} = -0.4V
Base Cutoff Current	I _{BL}	—	-100	nA	V _{CE} = -35V, V _{EB(off)} = -0.4V
ON CHARACTERISTICS (Note 7)					
DC Current Gain	h _{FE}	30	—	—	I _C = -100μA, V _{CE} = -1V I _C = -1.0mA, V _{CE} = -1V I _C = -10mA, V _{CE} = -1V I _C = -150mA, V _{CE} = -2V I _C = -500mA, V _{CE} = -2V
		60	—		
		100	—		
		100	300		
		20	—		
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	-0.4 -0.75	V	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	-0.75 —	-0.95 -1.3	V	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA
SMALL-SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	—	8.5	pF	V _{CB} = -10V, f = 1MHz
Input Capacitance	C _{ibo}	—	30	pF	V _{EB} = -0.5V, f = 1MHz
Input Impedance	h _{ie}	1.5	15	kΩ	V _{CE} = -10V, I _C = -1mA, f = 1kHz
Voltage Feedback Ratio	h _{re}	0.1	8	x 10 ⁻⁴	
Small-Signal Current Gain	h _{fe}	60	500	—	
Output Admittance	h _{oe}	1.0	100	μS	
Current Gain-Bandwidth Product	f _T	200	—	MHz	V _{CE} = -10V, I _C = -20mA, f = 100MHz
SWITCHING CHARACTERISTICS					
Delay Time	t _d	—	15	ns	V _{CC} = -30V, I _C = -150mA, V _{BE(off)} = -2V, I _{B1} = -15mA
Rise Time	t _r	—	20	ns	
Storage Time	t _s	—	225	ns	V _{CC} = -30V, I _C = -150mA, I _{B1} = I _{B2} = -15mA
Fall Time	t _f	—	30	ns	

Note: 7. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

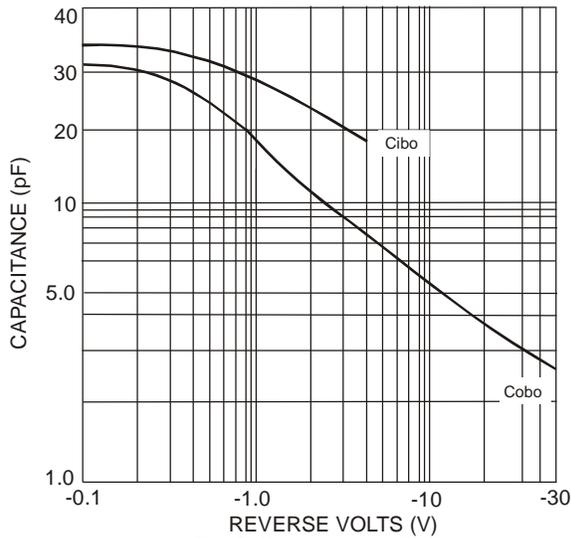


Fig. 2 Capacitances (Typical)

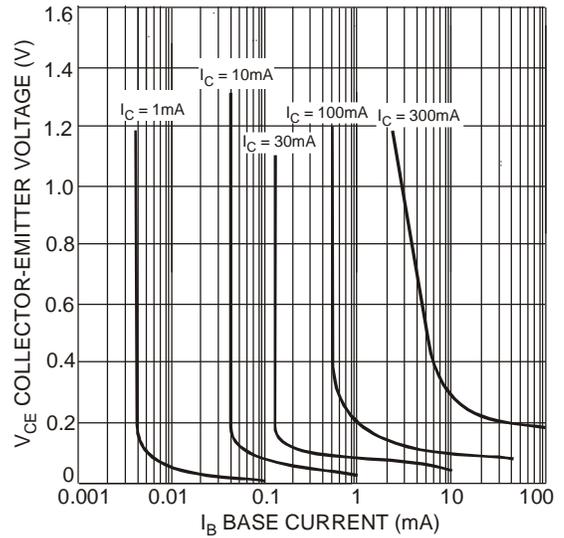


Fig. 3 Typical Collector Saturation Region

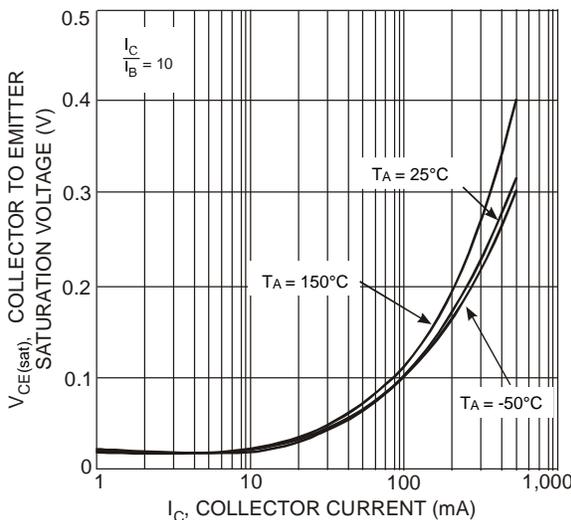


Fig. 4 Collector Emitter Saturation Voltage vs. Collector Current

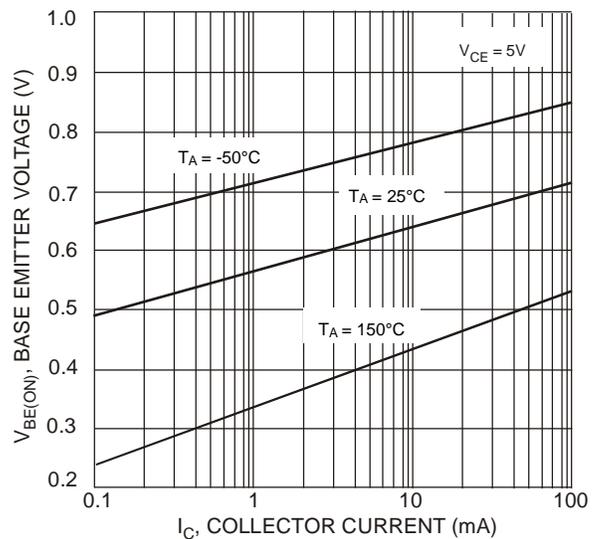


Fig. 5 Base-Emitter Voltage vs. Collector Current

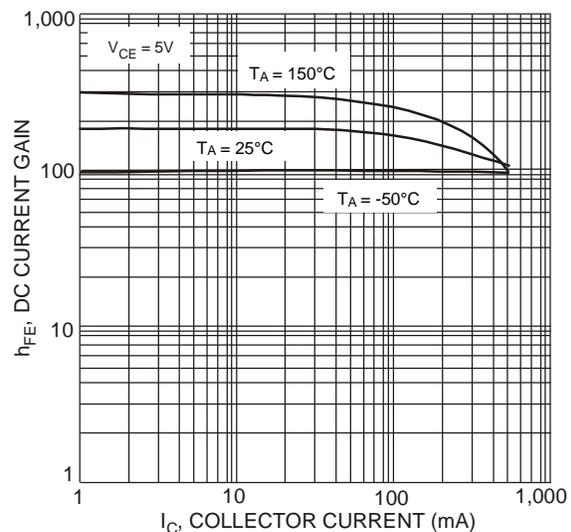


Fig. 6 DC Current Gain vs. Collector Current

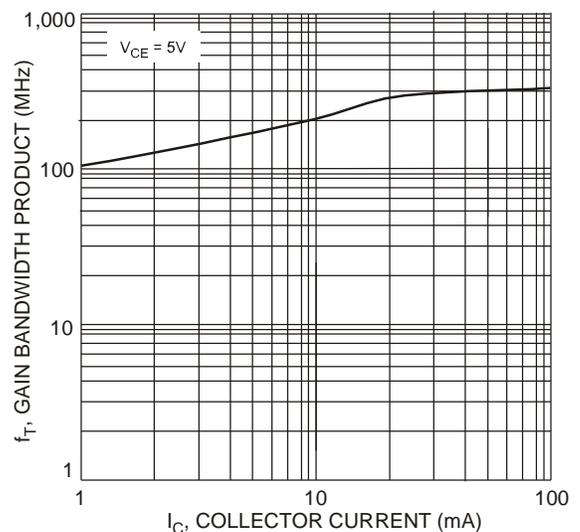
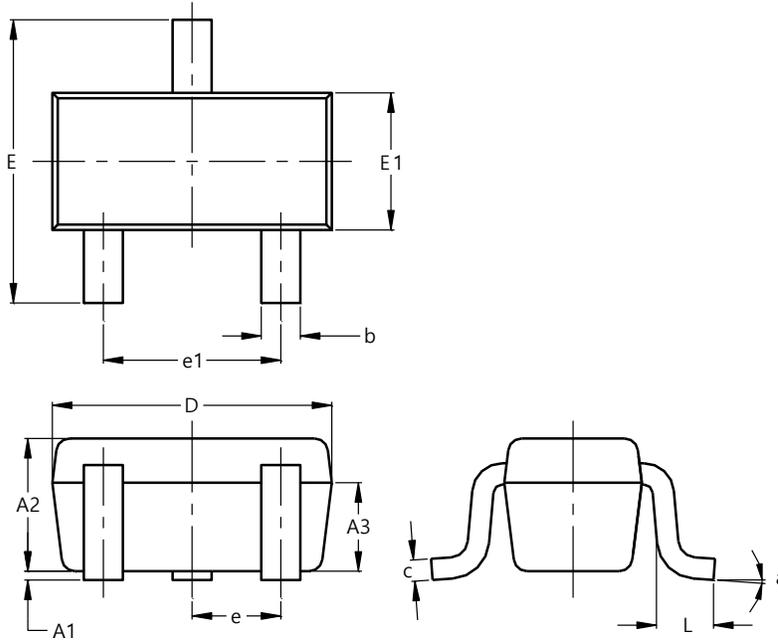


Fig. 7 Gain Bandwidth Product vs. Collector Current

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

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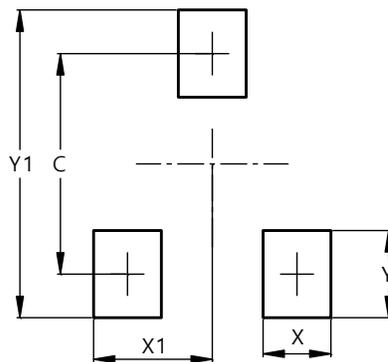


SOT523			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.60	0.80	0.75
A3	0.45	0.65	0.50
b	0.15	0.30	0.22
c	0.10	0.20	0.12
D	1.50	1.70	1.60
E	1.45	1.75	1.60
E1	0.75	0.85	0.80
e	0.50 BSC		
e1	0.90	1.10	1.00
L	0.20	0.40	0.33
a	0°	--	8°
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT523



Dimensions	Value (in mm)
C	1.29
X	0.40
X1	0.70
Y	0.51
Y1	1.80

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